



Product Change Notification / LIAL-25WABT393

Date:

09-May-2023

Product Category:

Power Discrete Components

PCN Type:

Manufacturing Change

Notification Subject:

CCB 6225 Initial Notice: Implementation of Die Overcoat material with Polyimide layer selected Microsemi SIC MOSFET product of MSCxxxSMA070, MSCxxxSMA120, and MSCxxxSMA170 device families in DICE, SOT-227, TO-247, TO-263 and TO-268 packages.

Affected CPNs:

[LIAL-25WABT393_Affected_CPN_05092023.pdf](#)

[LIAL-25WABT393_Affected_CPN_05092023.csv](#)

Notification Text:

PCN Status:Initial Notification

PCN Type:Manufacturing Change

Microchip Parts Affected:Please open one of the files found in the Affected CPNs section.

Note: For your convenience Microchip includes identical files in two formats (.pdf and .xls)

Description of Change:Implementation of Die Overcoat material with Polyimide layer selected Microsemi SIC MOSFET product of MSCxxxSMA070, MSCxxxSMA120, and MSCxxxSMA170 device families in DICE, SOT-227, TO-247, TO-263 and TO-268 packages.

Pre and Post Change Summary:

Method to Identify Change:Traceability code

Qualification Plan:Please open the attachments included with this PCN labeled as PCN_#_Qual_Plan.

Revision History:May 09, 2023: Issued initial notification.

The change described in this PCN does not alter Microchip's current regulatory compliance regarding the material content of the applicable products.

Attachments:

[PCN_LIAL-25WABT393 Qual_Plan.pdf](#)

Please contact your local [Microchip sales office](#) with questions or concerns regarding this notification.

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MICROCHIP
QUALIFICATION PLAN SUMMARY

PCN #: LIAL-25WABT393

Date:
March 23, 2023

Implementation of Die Overcoat material with Polyimide layer for selected Microsemi SIC MOSFET product of MSCxxxSMA070, MSCxxxSMA120, and MSCxxxSMA170 device families in DICE, SOT-227, TO-247, TO-263 and TO-268 packages.

Purpose: Implementation of Die Overcoat material with Polyimide layer selected Microsemi SIC MOSFET product of MSCxxxSMA070, MSCxxxSMA120, and MSCxxxSMA170 device families in DICE, SOT-227, TO-247, TO-263 and TO-268 packages.

CCB No. 6225

Test Name	Conditions	Reliability Stress Read Point	Pre & Post Reliability Stress Test Temperature	Sample Size	Min. Qty of Spares per Lot (should be properly marked)	Qty of Lots	Total Units	Fail Accept Qty	Est. Dur. Days	Special Instructions
MOSFET, IGBT, Transistors, Diodes, Zener diodes, Thyristors, LED	Tests we included in our qual plan templates will need to convert to MCHP formatting for CCB	Unless other wise specified the electrical ambient test temperature will be -40C to +125C equivalent to Q100 Grade 1.		***** New Process Qualification Requires 3 Lots			0			Discrete products delivered as stand alone, bare die or in wafer form are still qualified to Q101 using appropriate carriers or surrogate packages.
Assembly Data Requirements	MCHP Spec. FRM-39000-001									Use form FRM-39000-001 for assembly data collection.
Preconditioning - Required for surface mount devices	J-STD-020 JESD22-A113 +150°C Bake for 24 hours, moisture loading requirements per MSL level + 3X reflow at peak reflow temperature per Jedec-STD-020 for package type.		+25°C	231	15	3 from Assembly	738	0	15	Spares should be properly identified. TEST before and after PC.

Test Name	Conditions	Reliability Stress Read Point	Pre & Post Reliability Stress Test Temperature	Sample Size	Min. Qty of Spares per Lot (should be properly marked)	Qty of Lots	Total Units	Fail Accept Qty	Est. Dur. Days	Special Instructions
External Visual	JESD22-B101			All devices prior to submission for qualification testing	0	3 from Wafer	ALL	0	5	Inspect part construction, marking and workmanship.
Parametric Verification (Characterization)	Individual AEC user specification. Must be performed on the specific part.			25	5	3 from Wafer	90	0		Spares should be properly identified.
High Temperature Reverse Bias	MIL-STD-750 TM1038, test cond A, for diodes MIL-STD-750-1 M1039.4.2.2.1, test cond A for MOSFET or IGBT transistors Vdss: 100% of Device Rated Tj: xxx Duration: 1000 hours	<u>1st Readpoint:</u> 1000 hrs	+25°C	77	5	3 from Wafer	246	0	42 - 84	Spares should be properly identified.
High Temperature Gate Bias	JESD22A-108	<u>1st Readpoint:</u> 1000 hrs	+25°C	77	5	3 from Wafer	246	0	42 - 84	Spares should be properly identified.
Negative High Temperature Gate Bias (Required for SiC only)	JESD22-A-108 t = 1000 Hours @ Tj=xxx°C, Rated VRRM, Vgss: 100% Of Device Rated Can reduce duration to 500 hours by increasing Tj by 25°C	1000hrs	+25°C	77	5	3 from Wafer	246	0		

Test Name	Conditions	Reliability Stress Read Point	Pre & Post Reliability Stress Test Temperature	Sample Size	Min. Qty of Spares per Lot (should be properly marked)	Qty of Lots	Total Units	Fail Acce pt Qty	Est. Dur. Days	Special Instructions
Temp Cycle With Pre-conditioning	JESD22-A104 and Appendix 6 or MIL-STD-750 TM 1051 cond TBD by device specifcation.	[SiC devices] <u>1st Readpoint:</u> 400 cycles (-55°C to +175°C) per AEC-Q101 requirements	+25°C	77	5	3 from Assembly	246	0	15 - 120	Spares should be properly identified. PC before TC for surface mount devices.
uHAST With Pre-conditioning	JESD22-A118 +130°C/85% RH for 96 hrs Vds: 0 V	96 hrs	+25°C	77	5	3 from Assembly	246	0	10	Spares should be properly identified. PC before uHAST for surface mount devices. TEST before and after uHAST.
HAST With Pre-conditioning	JESD22-A110 +130°C/85% RH for 96 hrs or +110°C/85%RH for 264 hrs	<u>1st Readpoint:</u> 96 hrs (+130°C/85% RH) or 264 hrs (+110°C/85%RH)	+25°C	77	5	3 from Assembly	246	0	10 - 22	Spares should be properly identified. PC before HAST for surface mount devices.

Test Name	Conditions	Reliability Stress Read Point	Pre & Post Reliability Stress Test Temperature	Sample Size	Min. Qty of Spares per Lot (should be properly marked)	Qty of Lots	Total Units	Fail Accept Qty	Est. Dur. Days	Special Instructions
Intermittent Operational Life With Pre-conditioning	MIL-STD-750 Method 1037 [hermetic discrete products] or MIL-STD-750 TM1042, test cond D for MOSFET or IGBT transistors Number of Cycles: 10,000 Cycles (Extra 5k Minutes with 10k cycles, only actually need 9,230) Duty Cycle: 180 s Powered, 210 s Cooling , ΔT_j : 100°C With this duty cycle, could Reduce to 5k Cycles (4615) with ΔT_j : 125°		+25°C	77	5	3 from Assembly	246	0		Spares should be properly identified. PC before IOL for surface mount devices.
ESD Characterization	HBM per AEC Q101-001, and CDM per Q101-005 (must be performed on the specific part)			30 each HBM / CDM	0	1 from Wafer	30 each HBM / CDM	0		
Destructive Physical Analysis	AEC-Q101-004 Section 4			2	0	1 from Assembly	2	0		
Physical Dimensions	JESD22-B100			30	0	1 from Assembly	30	0		

Test Name	Conditions	Reliability Stress Read Point	Pre & Post Reliability Stress Test Temperature	Sample Size	Min. Qty of Spares per Lot (should be properly marked)	Qty of Lots	Total Units	Fail Accept Qty	Est. Dur. Days	Special Instructions
Terminal Strength	MIL-STD-750 Test Method 2036, cond D			30	0	1 from Assembly	30	0		
Resistance to Solder Heat With Pre-conditioning	JESD22-A111 (SMD) JESD22-B106 (PTH)			30	0	1 from Assembly	30	0		
Solderability	J-STD-002 JESD22B102			10	0	1 from Assembly	10	0		
Whisker Growth Evaluation	AEC-Q005					Assembly				
Thermal Resistance	JESD24-3, 24-4, 24-6 as appropriate			10 each, pre- & post-change	0	1 from Assembly	10 each, pre- & post-change	0		
Wire Bond Strength	MIL-STD-750 Method 2037			10 bonds from min of 5 parts	0	1 from Assembly	10 bonds from min of 5 parts	0		
Bond Shear	AEC-Q101-003			10 bonds from min of 5 parts	0	1 from Assembly	10 bonds from min of 5 parts	0		
Die Shear	MIL-STD-750 Method 2017			5	0	1 from Assembly	5	0		

Test Name	Conditions	Reliability Stress Read Point	Pre & Post Reliability Stress Test Temperature	Sample Size	Min. Qty of Spares per Lot (should be properly marked)	Qty of Lots	Total Units	Fail Accept Qty	Est. Dur. Days	Special Instructions
Unclamped Inductive Switching	AEC-Q101-004 Section 2 Running to Datasheet Characterization			5	0	1 from Assembly	5	0		
Dielectric Integrity (Power MOSFET and IGBTs)	AEC-Q101-004 Section 3			5	0	1 from Wafer	5	0		
Short Circuit Reliability Characterization	AEC-Q101-006			10	0	3 from Wafer	30	0		

LIAL-25WABT393 - CCB 6: MSCxxxSM and MSCx SOT-227 TO-247 TO-263 and TO-268 packages.

Affected Catalog Part Numbers(CPN)

MSC035SMA070B
MSC035SMA070B4
MSC035SMA070S
MSC017SMA120B
MSC017SMA120B4
MSC017SMA120S
MSC017SMA120J
MSC040SMA120B
MSC040SMA120B4
MSC040SMA120S
MSC040SMA120J
MSC040SMA120S/TR
MSC035SMA170B
MSC035SMA170B4
MSC035SMA170S
MSC015SMA070B
MSC015SMA070B4
MSC015SMA070S
MSC180SMA120B
MSC180SMA120S
MSC180SMA120SA
MSC360SMA120B
MSC360SMA120S
MSC360SMA120SA
MSC025SMA120B
MSC025SMA120B4
MSC025SMA120S
MSC025SMA120J
MSC080SMA120B
MSC080SMA120B4
MSC080SMA120S
MSC080SMA120J
MSC750SMA170B
MSC750SMA170B4
MSC750SMA170S
MSC750SMA170SA
MSC090SMA070B
MSC090SMA070S
MSC090SMA070SA
MSC060SMA070B
MSC060SMA070B4
MSC060SMA070S

MSC035SMA070D/S
MSC017SMA120D/S
MSC017SMA120D/SVAO
MSC040SMA120D/S
MSC040SMA120D/SVAO
MSC035SMA170D/S
MSC015SMA070D/S
MSC180SMA120D/S
MSC180SMA120D/SVAO
MSC360SMA120D/S
MSC360SMA120D/SVAO
MSC025SMA120D/S
MSC025SMA120D/SVAO
MSC080SMA120D/S
MSC080SMA120D/SVAO
MSC750SMA170D/S
MSC090SMA070D/S
MSC060SMA070D/S